



MAAPGM0040 RO-P-DS-3076 A Preliminary Information

### **Features**

- 0.5 Watt Saturated Output Power Level
- Variable Drain Voltage (4-10V) Operation
- ♦ MSAG<sup>™</sup> MESFET Process

### **Primary Applications**

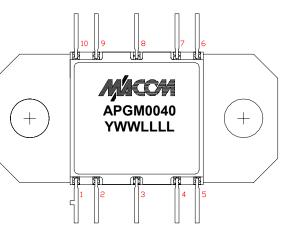
- Point-to-Point Radio
- Weather Radar
- Airborne Radar

### **Description**

The MAAPGM0040 is a packaged, 3-stage, 0.5W power amplifier with on-chip bias networks in a bolt down ceramic package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate MESFET Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG<sup>™</sup> process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



Pin Number	RF Designator		
1	No Connection		
2	No Connection		
3	RF IN		
4	No Connection		
5	V <sub>GG</sub>		
6	No Connection		
7	No Connection		
8	RF OUT		
9	No Connection		
10	V <sub>DD</sub>		

## Maximum Operating Conditions<sup>1</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	P <sub>IN</sub>	15.0	dBm
Drain Supply Voltage	V <sub>DD</sub>	+12.0	V
Gate Supply Voltage	$V_{GG}$	-3.0	V
Quiescent Drain Current (No RF, 40% IDSS)	I <sub>DQ</sub>	330	mA
Quiescent DC Power Dissipated (No RF)	P <sub>DISS</sub>	2.6	W
Junction Temperature	TJ	180	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C
Processing Temperature		230	°C

1. Operation outside of these ranges may reduce product reliability.

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

1

• North America Tel: 800.366.2266 / Fax: 978.366.2266

• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

• Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAAPGM0040 RO-P-DS-3076 A Preliminary Information

# **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур	Max	Unit
Drain Supply Voltage	V <sub>DD</sub>	4.0	8.0	10.0	V
Gate Supply Voltage	$V_{GG}$	-2.4	-2.0	-1.5	V
Input Power	P <sub>IN</sub>		10.0	13	dBm
Junction Temperature	TJ			150	°C
Thermal Resistance	Θ <sub>JC</sub>		34.9		°C/W
Package Base Temperature	Τ <sub>Β</sub>			Note 2	°C

2. Maximum Package Base Temperature = 150°C —  $\Theta_{JC}^* V_{DD}^* I_{DQ}$ 

### Electrical Characteristics: $T_B = 40^{\circ}$ C, $Z_0 = 50 \Omega$ , $V_{DD} = 8$ V, $I_{DQ} \approx 200 \text{ mA}^3$ , $P_{in} = 10 \text{ dBm}$ , $R_G \approx 350 \Omega$

Parameter	Symbol	Typical	Units		
Bandwidth	f	11.0-15.0	GHz		
Output Power	POUT	27	dBm		
Power Added Efficiency	PAE	27	%		
1-dB Compression Point	P1dB	26.5	dBm		
Small Signal Gain	G	20	dB		
Input VSWR	VSWR	2.7:1			
Output VSWR	VSWR	2.5:1			
Gate Supply Current	I <sub>GG</sub>	< 4	mA		
Drain Supply Current	I <sub>DD</sub>	< 300	mA		
Noise Figure	NF	8	dB		
2 <sup>nd</sup> Harmonic	2f	-20	dBc		
3 <sup>rd</sup> Harmonic	3f	-45	dBc		
Output Third Order Intercept	ΟΤΟΙ	33	dBm		
3 <sup>rd</sup> Order Intermodulation Distortion, Single Carrier Level = 21 dBm	IM3	-14	dBm		
5 <sup>th</sup> Order Intermodulation Distortion, Single Carrier Level = 21 dBm	IM5	-33	dBm		

#### 3. Adjust $V_{GG}$ between –2.4 to –1.5V to achieve indicated $I_{DQ}$ .



2

### **Operating Instructions**

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply  $V_{GG} \approx -1.8V$ ,  $V_{DD} = 0 V$ .
- 2. Ramp  $V_{DD}$  to desired voltage, typically 8 V.
- 3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (See Note 3 above).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn  $V_{GG}$  off last.
  - North America Tel: 800.366.2266 / Fax: 978.366.2266
  - Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
  - Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

M/A-COM Inc. and its affiliates reserve the right to make changes to the





MAAPGM0040 RO-P-DS-3076 A Preliminary Information

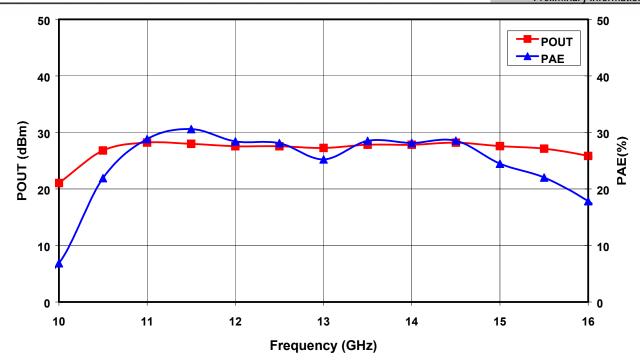
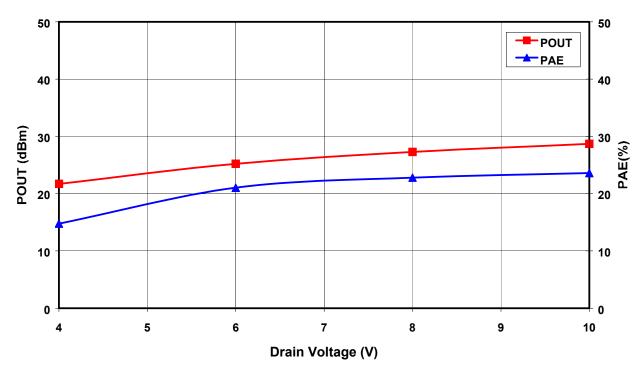
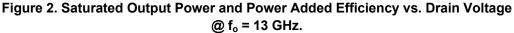


Figure 1. Output Power and Power Added Efficiency vs. Frequency @  $V_{DD}$  = 8V and  $P_{in}$  = 10 dBm.





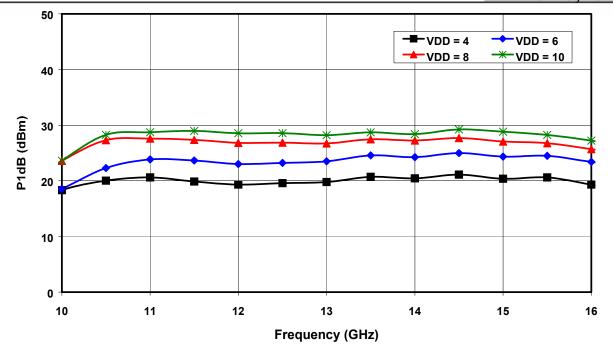
3

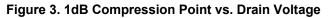
- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

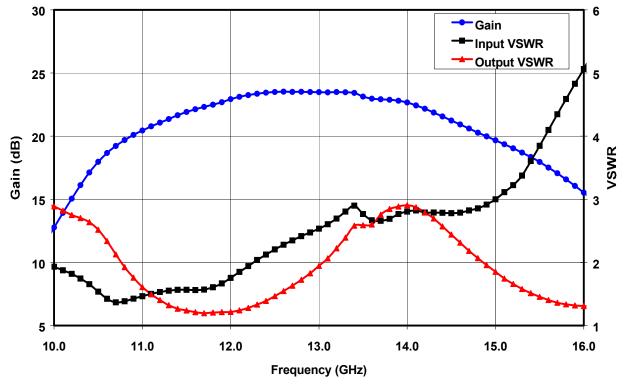


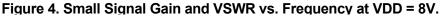


MAAPGM0040 RO-P-DS-3076 A Preliminary Information









4

- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAAPGM0040 RO-P-DS-3076 A Preliminary Information

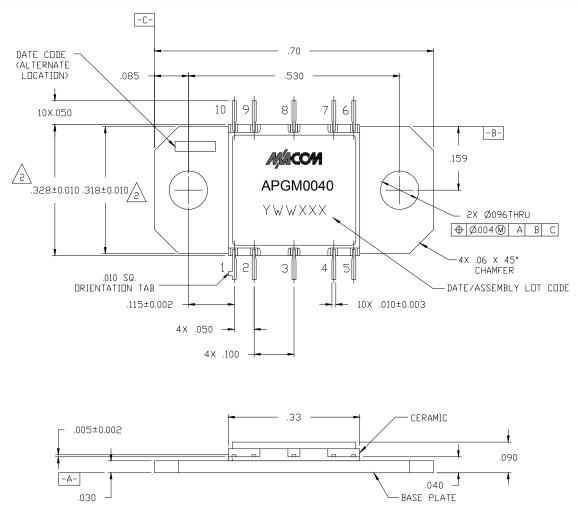


Figure 5. CR-15 Package Dimensions

The CR-15 is a high frequency, low thermal resistance package. The package consists of a cofired ceramic construction with a copper-tungsten base and iron-nickel-cobalt leads. The finish consists of electrolytic gold over nickel plate.

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

5

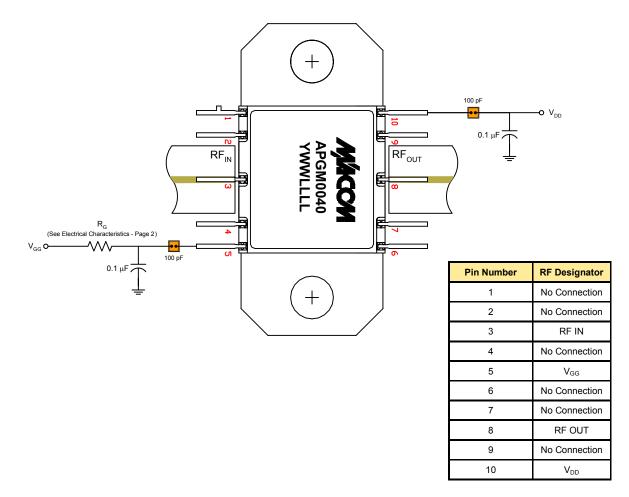
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAAPGM0040 RO-P-DS-3076 A Preliminary Information

### Figure 6. Recommended Bias Configuration



#### **Assembly Instructions:**

This flange mount style package provides a robust interface between a highly integrated GaAs MMIC device and a circuit board which may be assembled using conventional surface mount techniques. A thin shim made of a thermally and electrically conductive, ductile material should be used prior to installation of the CR-15 to improve the thermal and electrical performance of the package to housing interface. Refer to **M/A-COM Application Note #M567**\* for more information.

For applications where surface mount components are to be installed after the CR-15 installation, this package will not be damaged when subjected to typical convection or IR oven reflow profiles. Refer to **M/A-COM Application Note #M538**\* for maximum allowable reflow time and temperature. Alternatively, the package leads may be individually soldered. Whether an iron or hot gas soldering equipment is used, care should be taken to insure that the temperature is well controlled and electric static discharge (ESD) safe.

\* Application Notes can be found by going to the Site Search Page on M/A-COM's web page (http://www.macom.com/search/search.jsp) and searching for the required Application Note.

#### **Biasing Notes:**

- The 100pF bypass capacitors must be placed as close to the V<sub>GG</sub> and V<sub>DD</sub> pins as possible (recommended < 100 mils).</li>
- A negative bias must be applied to V<sub>GG</sub> before applying a positive bias to V<sub>DD</sub> to prevent damage to the amplifier.

6

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298